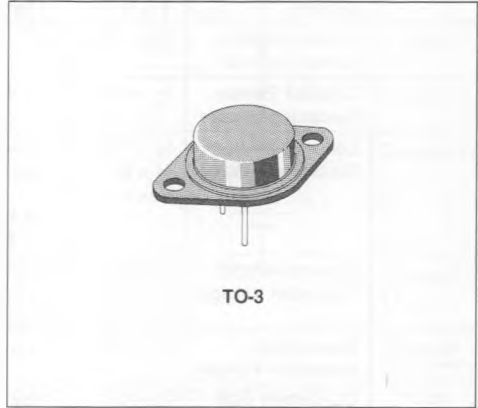
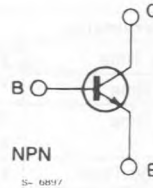


NPN HIGH VOLTAGE POWER TRANSISTORS

- SWITCHING REGULATORS
- INVERTERS
- SOLENOID AND RELAY DRIVERS
- MOTOR CONTROLS
- DEFLECTION CIRCUITS



INTERNAL SCHEMATIC DIAGRAM



DESCRIPTION

High voltage, high speed switching power transistors suited for use on the 220 and 380V mains.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	2N6674	2N6675	Unit
V_{CEV}	Collector-emitter Voltage ($V_{BE} = -1.5V$)	450	650	V
V_{CEX}	Collector-emitter Voltage	350	400	V
V_{CEO}	Collector-emitter Voltage ($I_C = 0$)	300	450	V
V_{EBO}	Emitter-base Voltage ($I_C = 0$)	7		V
I_C	Collector Current	15		A
I_{CM}	Collector Peak Current	20		A
I_B	Base Current	5		A
P_{tot}	Total Dissipation at $T_c < 25^\circ C$	175		W
T_{stg}	Storage Temperature	- 65 to 200		$^\circ C$
T_j	Max. Operating Junction Temperature	200		$^\circ C$

THERMAL DATA

$R_{thj-case}$	Thermal Resistance Junction-case	Max	1	°C/W
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ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Test Conditions			Min.	Typ.	Max.	Unit
I_{CEV}	Collector Cutoff Current	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$	$V_{BE} = -1.5V$ $V_{BE} = -1.5V$	$T_c = 100^{\circ}C$			0.1 1	mA mA
I_{EBO}	Emitter Cutoff Current ($I_C = 0$)	$V_{EB} = 7V$					2	mA
$V_{CEO(sus)}^*$	Collector Emitter Sustaining Voltage	$I_C = 0.2A$	$L_C = 25mH$	for 2N6674 for 2N6675	300 400			V V
$V_{CEX(sus)}^*$	Collector-emitter Sustaining Voltage	$I_C = 10A$ $I_B = 2A$ $V_{BB} = -4V$	$L_C = 50\mu H$ $R_{BB} = 2\Omega$	for 2N6674 for 2N6675	350 450			V V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 10A$ $I_C = 10A$ $I_C = 15A$	$I_B = 2A$ $I_B = 2A$ $I_B = 5A$	$T_c = 100^{\circ}C$			1 2 5	V V V
$V_{BE(sat)}^*$	Base-emitter Saturation Voltage	$I_C = 10A$	$I_B = 2A$				1.5	V
h_{FE}^*	DC Current Gain	$I_C = 10A$	$V_{CE} = 2V$		8			
h_{Ia}	Small Signal Current Gain	$I_C = 1A$	$V_{CE} = 10V$	$f = 5MHz$	3		10	

RESISTIVE LOAD

Symbol	Parameter	Test Conditions			Min.	Typ.	Max.	Unit
t_d	Delay Time	$V_{CC} = 135V$	$I_C = 10A$	$t_p = 20\mu s$			0.1	μs
t_r	Rise Time	$V_{BB} = -6V$	$I_{t\#} p = 20\mu s$				0.6	μs
t_r	Rise Time	$V_{CC} = 135V$ $V_{BB} = -6V$	$I_C = 10A$ $I_{B1} = 2A$	$t_p = 20\mu s$ $T_c = 100^{\circ}C$			1	μs
t_s	Storage Time	$V_{CC} = 135V$	$I_C = 10A$	$t_p = 20\mu s$			2.5	μs
t_f	Fall Time	$V_{BB} = -6V$	$I_{B1} = -I_{B2} = 2A$				0.5	μs
t_s	Storage Time	$V_{CC} = 135V$	$I_C = 10A$	$t_p = 20\mu s$			4	μs
t_f	Fall Time	$V_{BB} = -6V$ $T_c = 100^{\circ}C$	$I_{B1} = -I_{B2} = 2A$				1	μs

INDUCTIVE LOAD

Symbol	Parameter	Test Conditions			Min.	Typ.	Max.	Unit
t_c	Crossover Time	$V_{CC} = 135V$ $R_C = 13.5\Omega$ $V_{clamp} = V_{CEX}$	$I_C = 10A$ $I_{B1} = -I_{B2} = 2A$	$I_C = 50\mu H$ $T_c = 25^{\circ}C$ $T_c = 100^{\circ}C$			0.5 0.8	μs μs

* Pulsed : Pulse duration = 300 μs , duty cycle = 2 %.

Figure 1 : Test Circuit RBSOA.

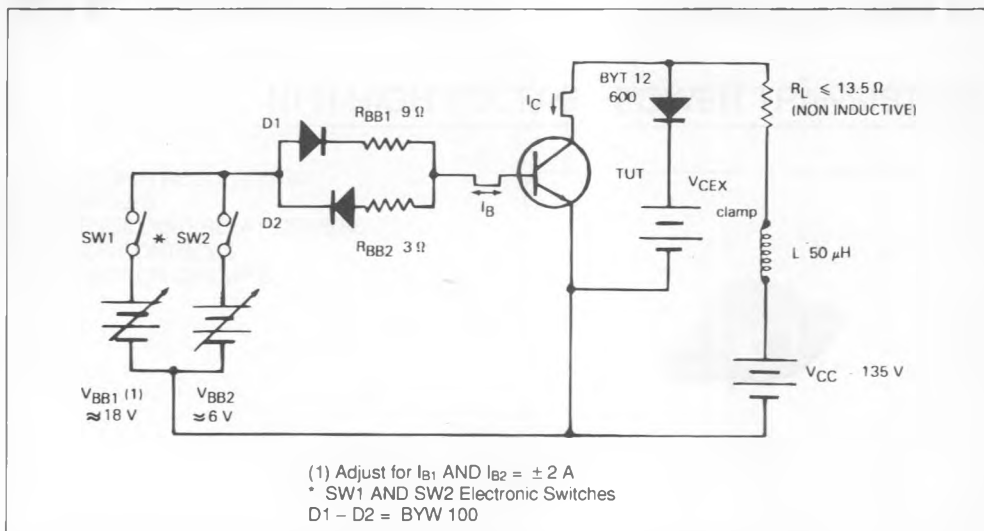


Figure 2 : Maximum Operating Conditions for Switching between Saturation and Cut-off.

